



CPH3115/CPH3215

DC/DC Converter Applications

Applications

- Relay drivers, lamp drivers, motor drivers, and strobes.

Features

- Adoption of MBIT processes.
- Large current capacitance.
- Low collector-to-emitter saturation voltage.
- High-speed switching.
- Ultrasmall-sized package permitting applied sets to be made small and slim (mounting height : 0.9mm).
- High allowable power dissipation.

Specifications

() : CPH3115

Absolute Maximum Ratings at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V_{CBO}		(-30)40	V
Collector-to-Emitter Voltage	V_{CEO}		(-30)	V
Emitter-to-Base Voltage	V_{EBO}		(-5)	V
Collector Current	I_C		(-1.5)	A
Collector Current (Pulse)	I_{CP}		(-3)	A
Base Current	I_B		(-300)	mA
Collector Dissipation	P_C	Mounted on a ceramic board (600mm ² ×0.8mm)	0.9	W
Junction Temperature	T_J		150	°C
Storage Temperature	T_{stg}		-55 to +150	°C

Electrical Characteristics at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	$V_{CB}=(-)30\text{V}, I_E=0$			(-0.1)	μA
Emitter Cutoff Current	I_{EBO}	$V_{EB}=(-)4\text{V}, I_C=0$			(-0.1)	μA
DC Current Gain	h_{FE}	$V_{CE}=(-)2\text{V}, I_C=(-)100\text{mA}$	200		560	
Gain-Bandwidth Product	f_T	$V_{CE}=(-)10\text{V}, I_C=(-)300\text{mA}$		(450)		MHz
				500		MHz
Output Capacitance	C_{ob}	$V_{CB}=(-)10\text{V}, f=1\text{MHz}$		(9)8		pF

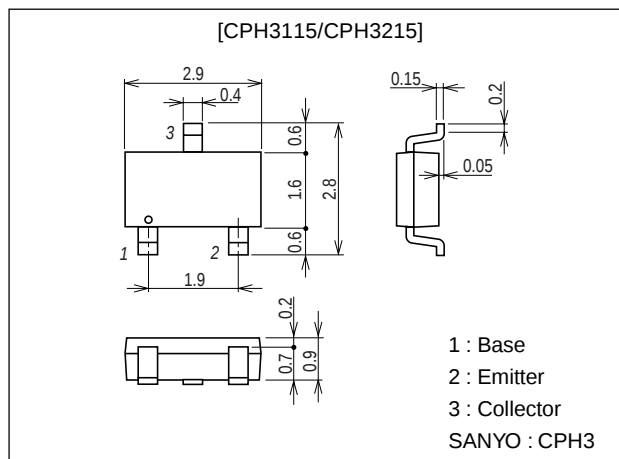
Marking : CPH3115 : AQ, CPH3215 : CQ

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Package Dimensions

unit:mm

2150A



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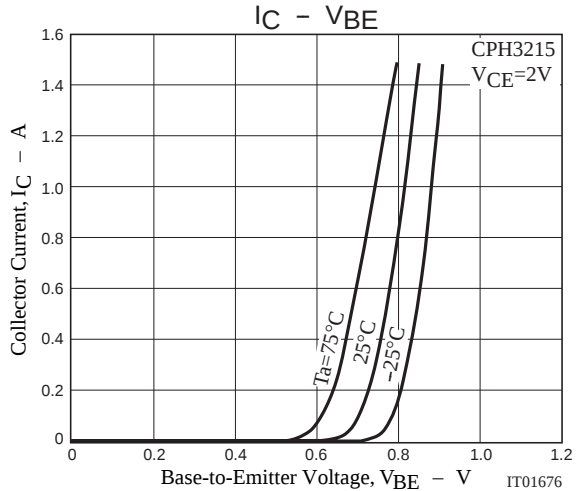
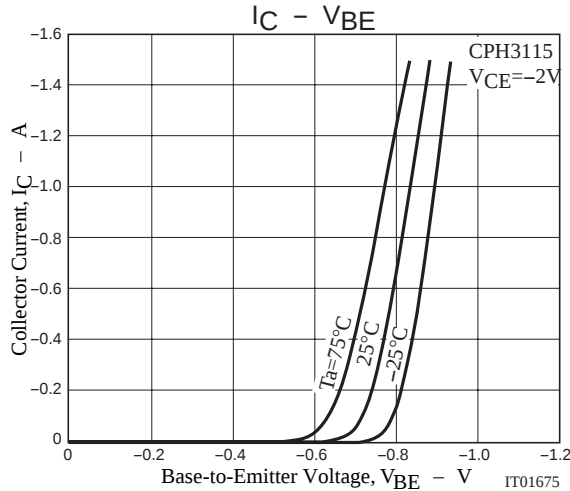
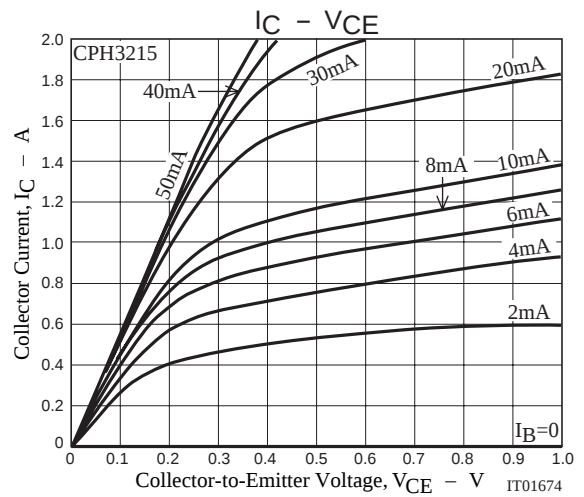
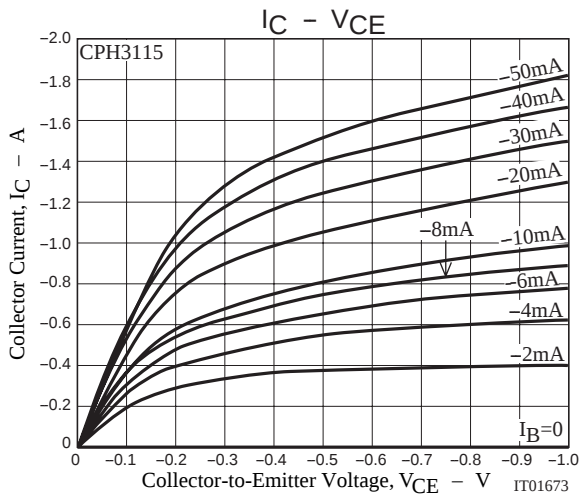
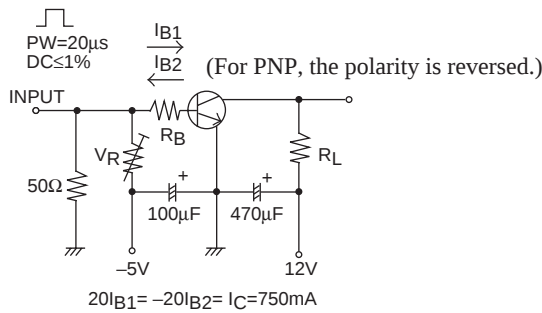
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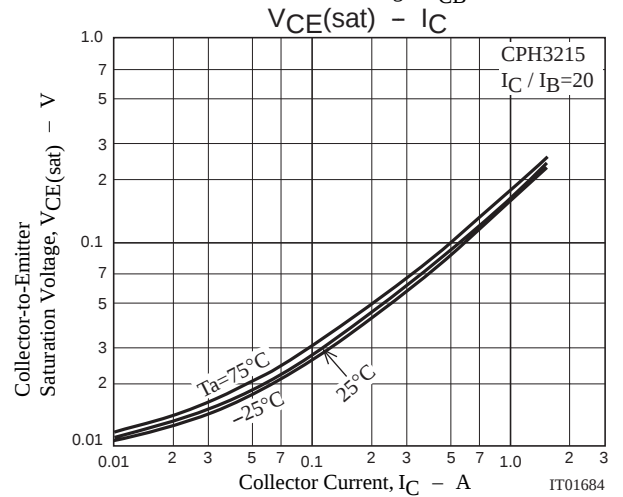
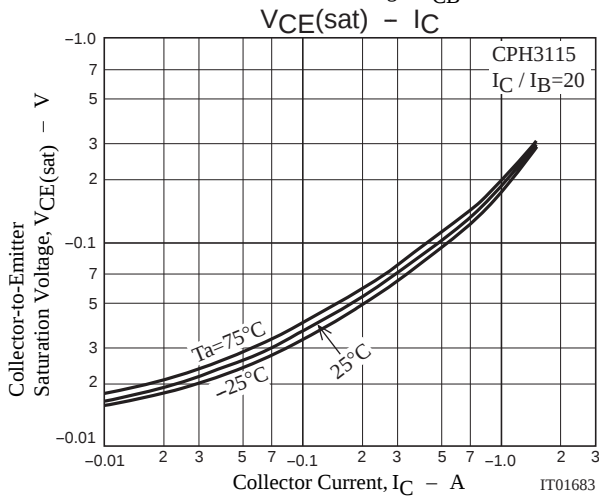
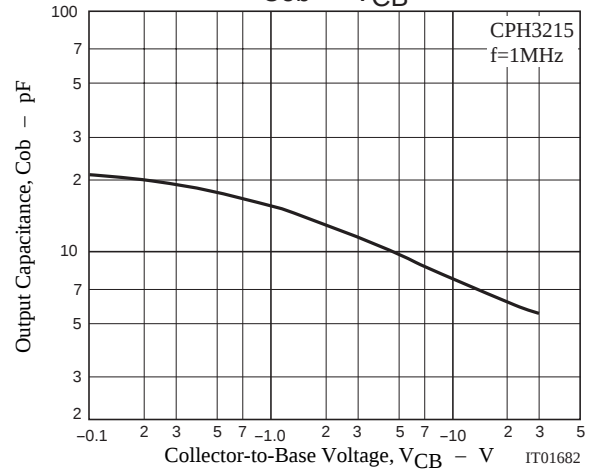
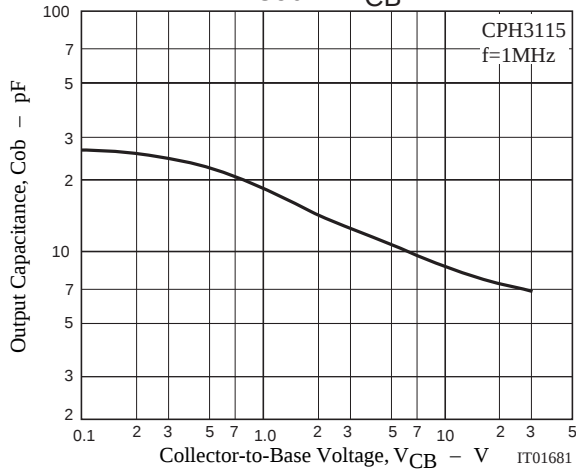
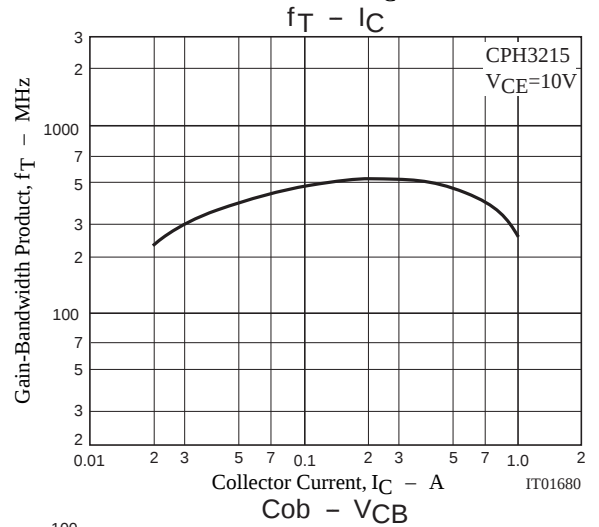
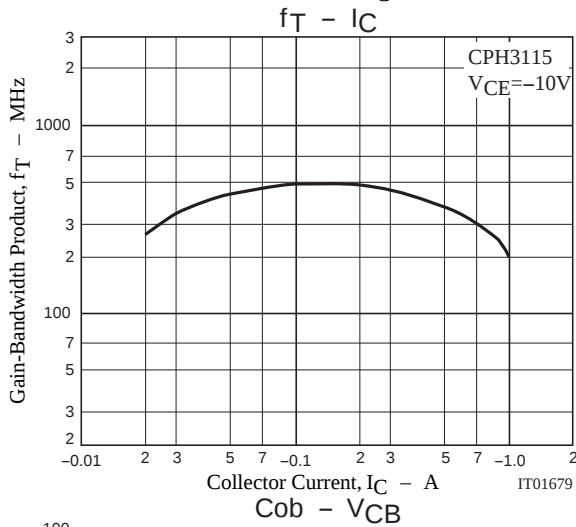
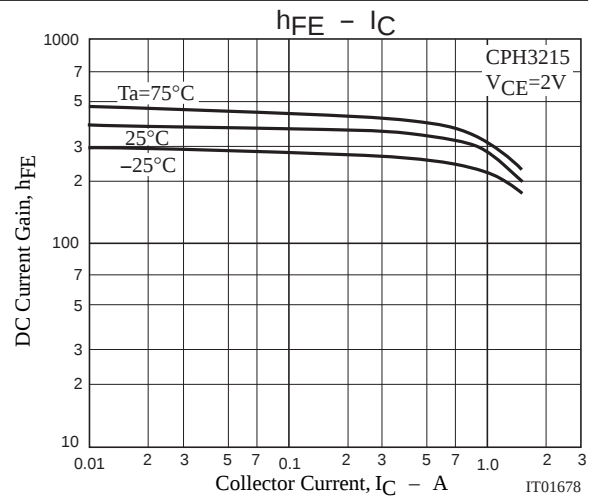
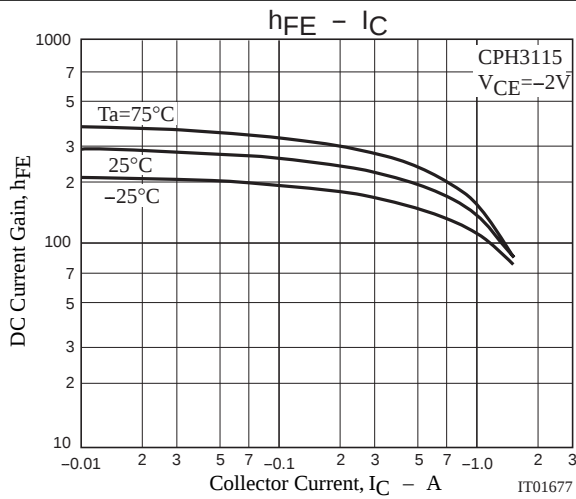
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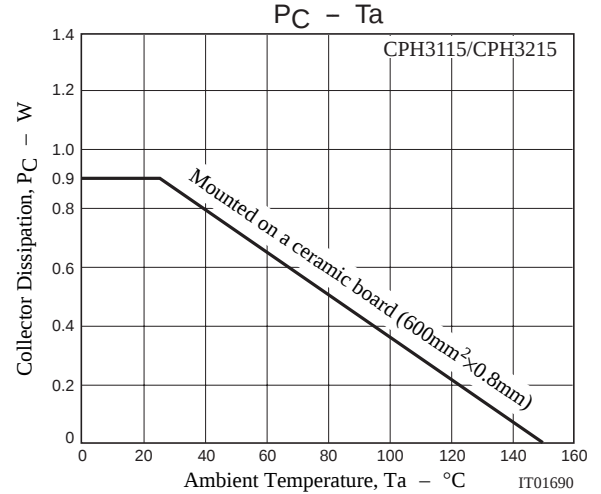
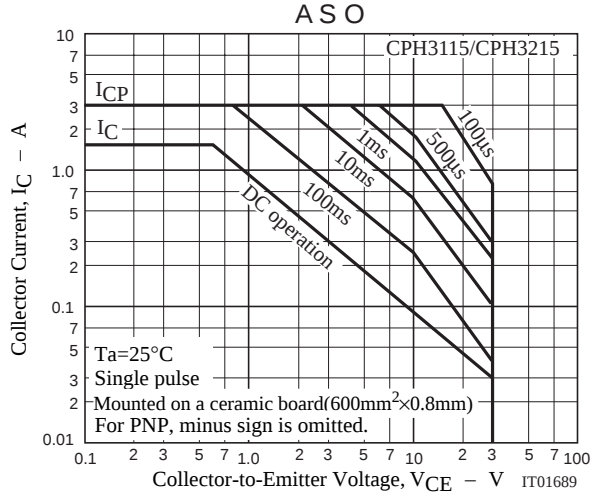
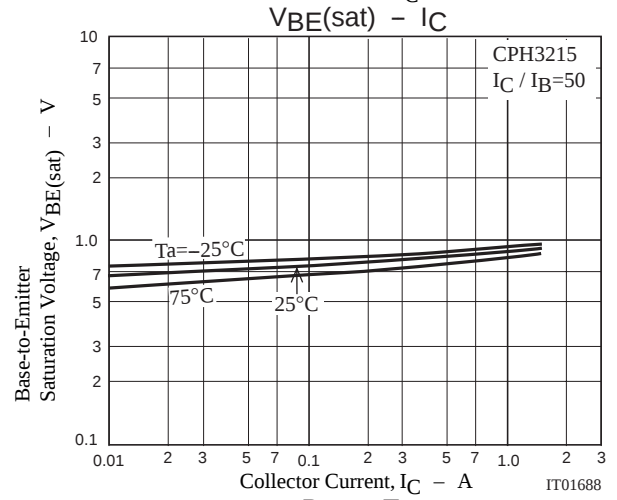
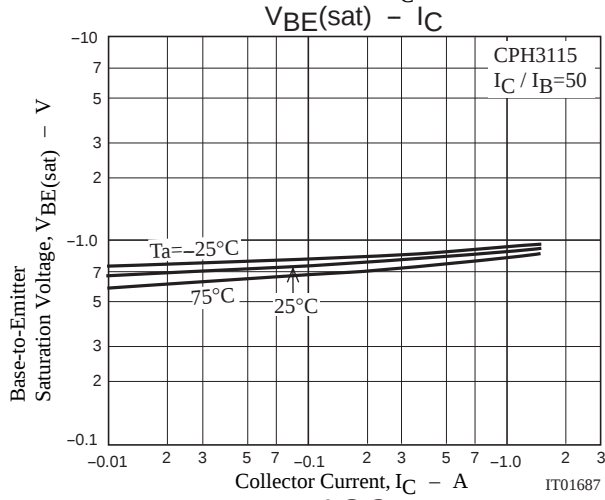
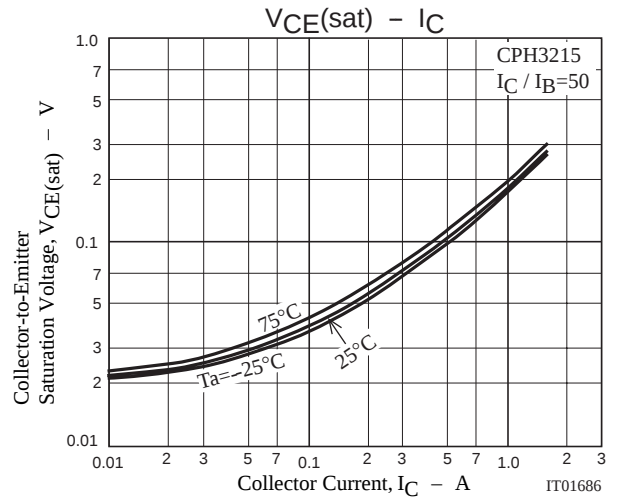
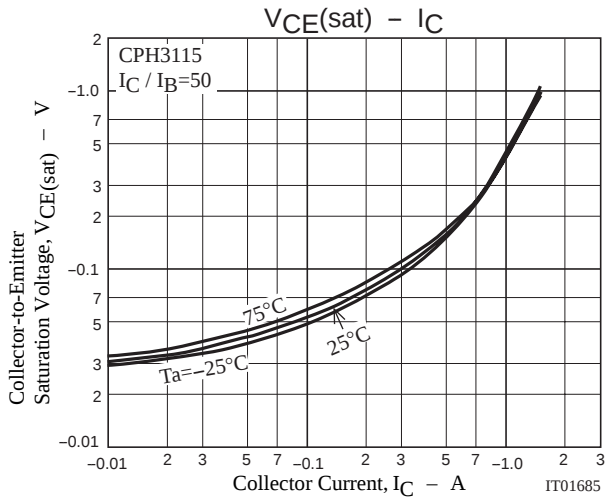
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=(-)750\text{mA}$, $I_B=(-)15\text{mA}$		(-250)	(-375)	mV
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=(-)750\text{mA}$, $I_B=(-)15\text{mA}$		150	225	mV
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=(-)10\mu\text{A}$, $I_E=0$	(-30)			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=(-)1\text{mA}$, $R_{BE}=\infty$	(-)30			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=(-)10\mu\text{A}$, $I_C=0$	(-)5			V
Turn-ON Time	t_{on}	See specified test circuit.		35		ns
Storage Time	t_{stg}	See specified test circuit.		(115)		ns
				205		ns
Fall Time	t_f	See specified test circuit.		30		ns

Switching Time Test Circuit



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